PROTON

JSC "Proton"

Photodiode array chip FM053P

Description

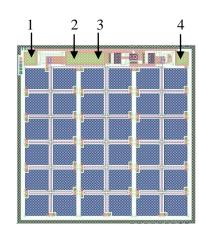
FM053P is designed to drive MOSFETs, including SiC MOSFETs, with threshold voltage 3-7 V and can be used in MOS-relay within one package or as a separate device. The spectral response range is 850-940 nm. The chip should be used for face-to-face coupling design together with two IR-LEDs in accordance with the PDA surface illumination scheme.

Absolute maximum ratings

Storage Temperature	-65°C to 150°C
Operating Junction Temperature	-55°C to 125°C

Features

- Contact pad's material Aluminium
- Contact pad's size 0.13 x 0.13 mm
- Module size 2.0 x 2.0 mm (including scribe line)
- Scribe line width 80 μm
- Chip thickness $0.32 \text{ mm} \pm 0.02 \text{ mm}$



- 1- Output
- 2 GND
- 3 GND
- 4 Output

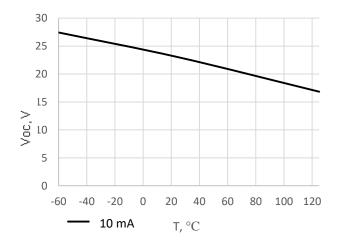
Electrical characteristics (T = 25 °C)

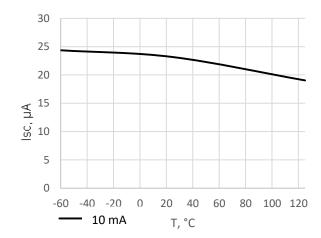
Parameter	Symbol	Unit	Min.	Typ.	Max.	Condition
Open Circuit Voltage	V _{OC}	V	18.0	20.0	-	1
Open Circuit Voltage	V _{OC}	V	-	22	-	2
Short Circuit Current	I_{SC}	μΑ	1.6	2.2	-	1
Short Circuit Current	I_{SC}	μΑ	-	23		2
Output Voltage	$V_{\rm O}$	V	-	-	0.9	3
Turn-On Time	T _{ON}	ms	-	0.6	1	4
Turn-Off Time	T_{OFF}	ms	-	0.05	0.3	4

- 1 Light source with peak wavelength λ = 850 ±20 nm that provides surface irradiance $E = 20 \text{ mW/cm}^2$ is used.
- 2 Testing condition: I_F = 10 mA. The PDA is assembled with two IR-LEDs of P = 2000 μ W (at 10 mA) each with peak wavelength λ = 850 \pm 20 nm.
- $3 \text{No light. } I_0 = 100 \,\mu\text{A}$
- 4- Typical value at $I_F=10$ mA, $C_L=1000$ pF. The PDA is assembled with two LEDs of $P=2000~\mu W$ (at 10 mA) each with peak wavelength $\lambda=850\pm20$ nm. The measurement was performed in accordance with the specified testing circuit and diagram.

Typical characteristics

Typical characteristics` measurement is performed on PDA chip assembled with IR-LED chip of P = 2000 μ W (at 10 mA) with peak wavelength λ = 850 \pm 20 nm. The recommended IR-LED chips` location is specified at PDA surface illumination scheme.

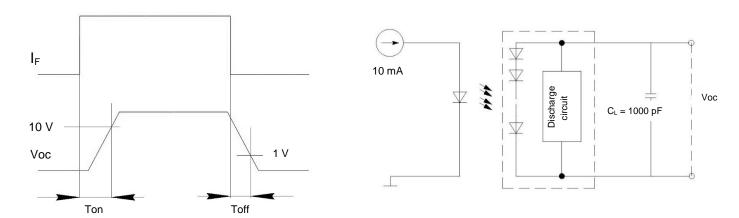




Picture 1 – typical characteristics $V_{OC}(T)$

Picture 2 – typical characteristics I_{SC} (T)

Dynamic parameters testing circuit and diagram



PDA surface illumination scheme

